Form PTO-1449 (Rev. 2-32) U.S. Department of Commerce Patent & Trademark Office	Atty. Docket No. Q62494	Serial No.: ~~Confirmation No.~~: 09/817,233
INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)	Applicant: Ryo KUBOTA, et al.	
	Filing Date: March 27, 2001	Group: ~~Unknown~~ 2823

U.S. PATENT DOCUMENTS

Examiner Initial		Document Number	Date	Name	Class	Sub-Class	Filing Date (if appropriate)

FOREIGN PATENT DOCUMENTS

		Document	Date	Country	Class	Sub-class	Translation Yes/No
Lee		11-284139	10/15/99	Japan			

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

Lee		H. Watanabe et al., "Hemispherical Grained Si Formation on in-situ Phosphorus Doped Amorphous-Si Electrode for 256Mb DRAM's Capacitor", IEEE Transactions on Electron Devices, Vol. 42, No. 7, (July 1995), pp. 1247-1254 with Abstract.

EXAMINER: Kevin Min Lee DATE CONSIDERED: 6/21/02

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